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High Performance Schottky Rectifier, 1.0 A



SMB (DO-214AA)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	1.0 A			
V _R	15 V			
V _F at I _F	0.21 V			
I _{RM}	35 mA at 100 °C			
T _J max.	125 °C			
E _{AS}	1.0 mJ			
Package	SMB (DO-214AA)			
Circuit configuration	Single			

FEATURES

- · Low forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability
- 125 °C T_J operation ($V_R < 5 V$)
- · Optimized for OR-ing applications
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-10BQ015-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	1.0	А	
V _{RRM}		15	V	
I _{FSM}	t _p = 5 μs sine	140	А	
V _F	1.0 A _{pk} , T _J = 125 °C	0.21	V	
TJ	Range	-55 to +125	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10BQ015-M3	UNITS	
Maximum DC reverse voltage	V _R	15	V	
Maximum working peak reverse voltage	V _{RWM}	25	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_L = 134 °C, rectangular waveform		1.0	А
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse Following any rated load		140	
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	40	A
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 2 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{EM} ⁽¹⁾	1 A	T _{.1} = 25 °C	0.33	V
		2 A	1j=25 0	0.39	
	VFM \''	1 A	T _J = 125 °C	0.21	
		2 A		0.29	
Maximum reverse leakage current		T _J = 25 °C		0.5	mA
See fig. 2	I _{RM}	T _J = 100 °C	$V_R = Rated V_R$	35	
Threshold voltage	V _{F(TO)}	$T_{J} = T_{J}$ maximum		-	V
Forward slope resistance	r _t			-	mΩ
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		390	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		-55 to +125	°C
Maximum storage temperature range	T _{Stg}		-55 to +150	C
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	36	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	C/W
Approvimente uneight			0.10	g
Approximate weight			0.003	oz.
Marking device		Case style SMB (DO-214AA) 1C		С

Notes

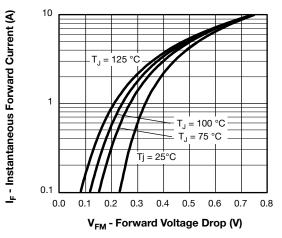
(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB

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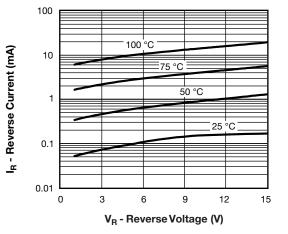
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Fig. 1 - Maximum Forward Voltage Drop Characteristics





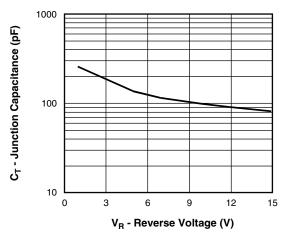


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

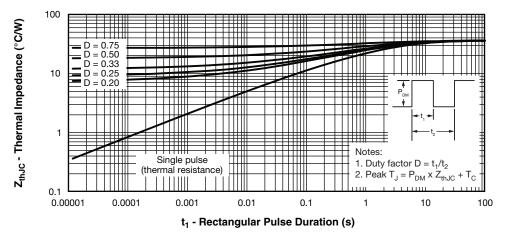


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

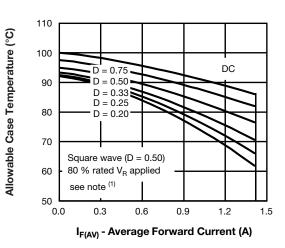
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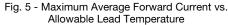


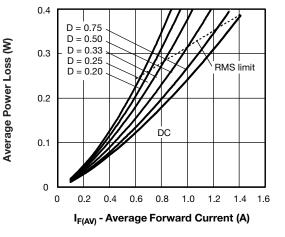
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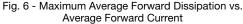


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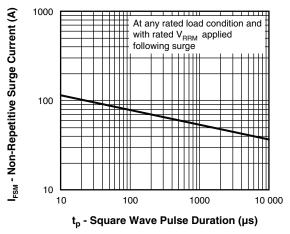


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

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ORDERING INFORMATION TABLE

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Device code	VS-	10	в	Q	015	-M3
		2	3	4	5	6
	 Vishay Semiconductors product Current rating 					
	3 - B = SMB					
	4 -	Q =	Schottk	ky "Q" se	eries	
	5 - Voltage rating (015 = 15 V)					
	6 - Environmental digit:					

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-10BQ015-M3/5BT	5BT	3200	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95401
Part marking information	www.vishay.com/doc?95403
Packaging information	www.vishay.com/doc?95404
SPICE model	www.vishay.com/doc?95666

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